



LED Display

Product Data Sheet

LTP-2557KS

Spec No.: DS30-2007-0025

Effective Date: 05/16/2007

Revision: A

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

LITE-ON Technology Corp. / Optoelectronics

No.90,Chien 1 Road, Chung Ho, New Taipei City 23585, Taiwan, R.O.C.

Tel: 886-2-2222-6181 Fax: 886-2-2221-1948 / 886-2-2221-0660

<http://www.liteon.com/opto>

LED DISPLAY**LTP-2557KS**
DATA SHEET

<u>Rev</u>	<u>Description</u>	<u>By</u>
-	Original Spec	<u>Phanomkorn J.</u>
A	Revise average luminous intensity on page 5/6	<u>Phanomkorn J.</u>

S P E C . N O . : DS30-2007-0025

D A T E : 23/APRIL/'07

R E V . N O . : A

PAGE NO. : 0 OF 6

FEATURES

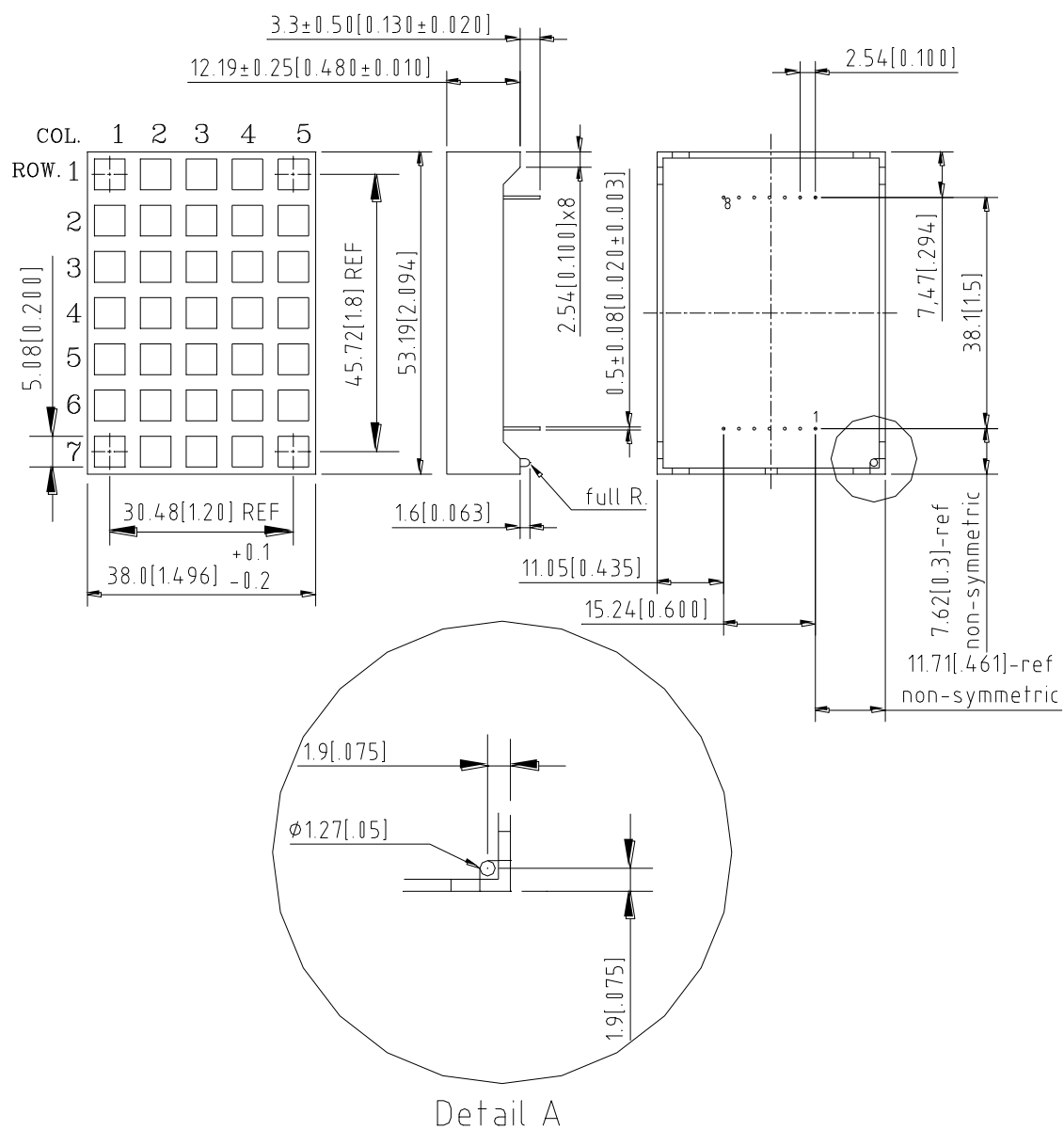
- * 2 inch (50.8 mm) MATRIX HEIGHT.
- * LOW POWER REQUIREMENT.
- * SINGLE PLANE, WIDE VIEWING ANGLE
- * SOLID STATE RELIABILITY.
- * 5x7 ARRAY WITH X-Y SELECT.
- * COMPATIBLE WITH USASCLL AND EBCDIC CODES.
- * STACKABLE HORIZONTALLY.
- * CATEGORIZED FOR LUMINOUS INTENSITY.
- * **LEAD-FREE PACKAGE (ACCORDING TO ROHS)**

DESCRIPTION

The LTP-2557KS is a 2 inch (50.8 mm) matrix height 5x7 dot matrix display. This device utilizes AlInGaP Yellow LED chips, which are made from AlInGaP on a non-transparent GaAs substrate, and has a gray face and white dot color.

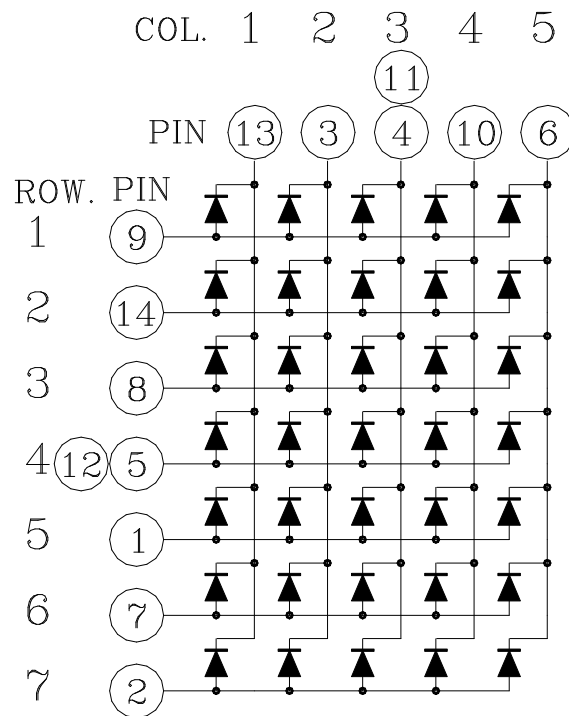
DEVICE

PART NO.	DESCRIPTION
AlInGaP Yellow	Cathode Column Anode Row
LTP-2557KS	

PACKAGE DIMENSIONS


- NOTES: 1. All dimensions are in millimeters. Tolerances are ± 0.25 mm unless otherwise note.
2. Pin tip's shift tolerance is ± 0.4 mm.

INTERNAL CIRCUIT DIAGRAM



PIN CONNECTION

No.	CONNECTION
1	ANODE ROW 5
2	ANODE ROW 7
3	CATHODE COLUMN 2
4	CATHODE COLUMN 3
5	ANODE ROW 4
6	CATHODE COLUMN 5
7	ANODE ROW 6
8	ANODE ROW 3
9	ANODE ROW 1
10	CATHODE COLUMN 4
11	CATHODE COLUMN 3
12	ANODE ROW 4
13	CATHODE COLUMN 1
14	ANODE ROW 2

ABSOLUTE MAXIMUM RATING AT T_A=25°C

PARAMETER	MAXIMUM RATING	UNIT
Average Power Dissipation Per Dot	70	mW
Peak Forward Current Per Dot	60	mA
Average Forward Current Per Dot	25	mA
Derating Linear From 25°C Per Dot	0.33	mA/°C
Reverse Voltage Per Dot	5	V
Operating Temperature Range	-35°C to +105°C	
Storage Temperature Range	-35°C to +105°C	

Soldering Conditions: 1/16 inch below seating plane for 3 seconds at 260°C

or of temperature unit (during assembly) not over max. temperature rating above.

ELECTRICAL / OPTICAL CHARACTERISTICS AT T_A=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _v	800	3600		μcd	I _p =32mA 1/16DUTY
Peak Emission Wavelength	λ _p		588		nm	I _F =20mA
Spectral Line Half-Width	Δλ		15		nm	I _F =20mA
Dominant Wavelength	λ _d		587		nm	I _F =20mA
Forward Voltage any Dot	V _F		2.05	2.6	V	I _F =20mA
Reverse Current any Dot	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio (Similar Light Area)	I _{v-m}			2:1		I _p =32mA 1/16DUTY

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

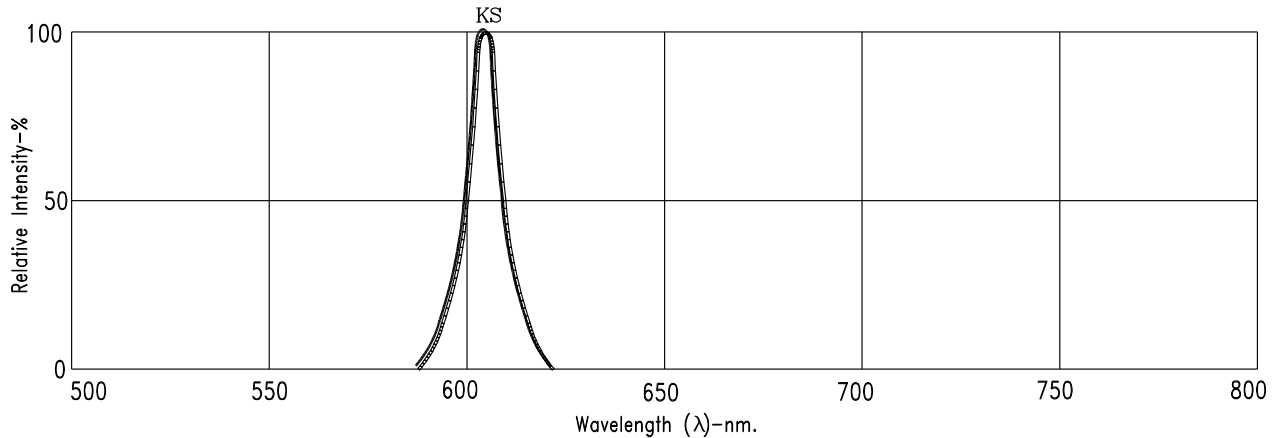


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

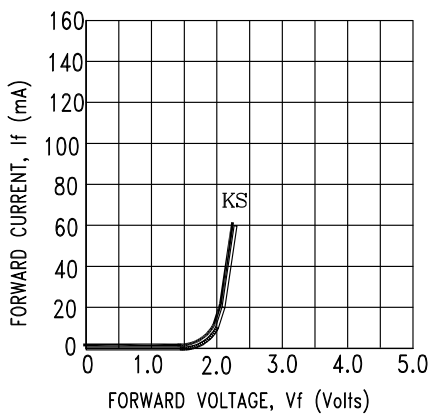


Fig2. Forward Current vs. Forward Voltage

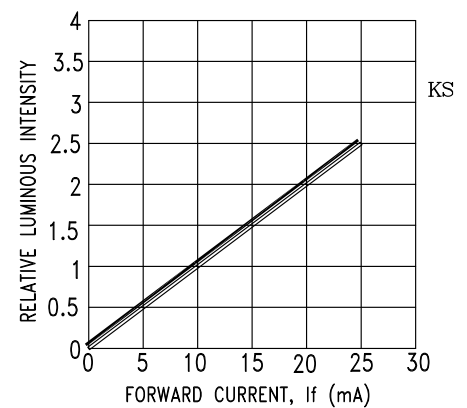


Fig3. Relative Luminous Intensity vs. DC Forward Current

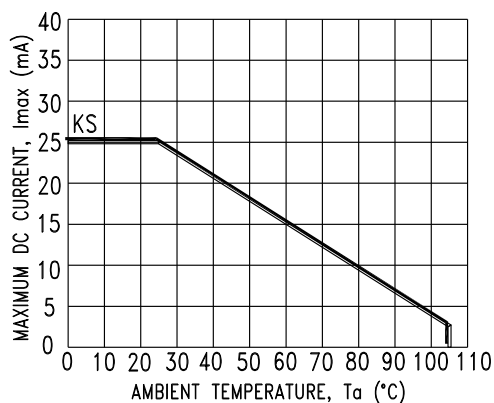


Fig4. Maximum Allowable DC Current vs. Ambient Temperature

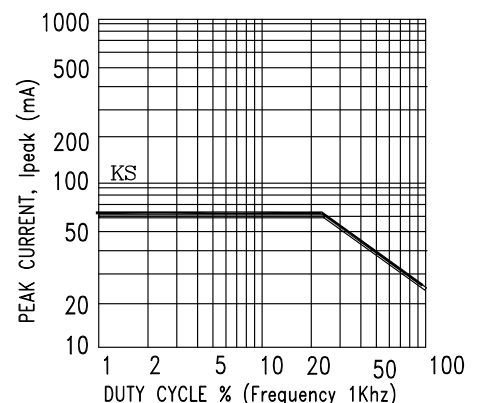


Fig5. Maximum Peak Current vs. Duty Cycle %

NOTE : KS=AlInGaP YEELOW